



M T B F

(E I A J R C R - 9 1 0 2)

Model	TUNS1200F65
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No.	P a r t s		Q'ty of Device	Failure rate [10 ⁻⁶ /H]	R e f e r e n c e
1	I C	Monolithic	15	0.6520	
2		Hybrid	0	0.0000	
3	Transistors		27	1.6940	
4	Diodes		38	0.6450	
5	LED•Optocouplers		6	0.4200	
6	Resistors		220	0.3730	
7	Capacitors		162	1.1988	
8	Transformer•Choke Coil		6	0.1150	
9	Connectors		1232	0.3472	
10	Others		2	0.1130	
Total Failure Rate [10 ⁻⁶ /H]				5.5580	

M T B F	[H]	180,000
Ambient Temperature	[℃]	—
Load Factor	[%]	—